Crystal Oscillator (SPXO)

· Package size (2.0 mm × 1.6 mm × 0.7 mm)

- Fundamental mode SPXO
- Output: CMOS

Reference weight Typ.9.9 mg

[1] Product Number / Product Name / Marking

(1-1) Product Number / Ordering Code

X1G0048010014xx

Last 2 digits $code(\mathbf{xx})$ defines Quantity.

The standard is "00", 3 000 pcs/Reel.

(1-2) Product Name / Model Name

SG2016CAN 16.000000 MHz TJGA

[2] Operating Range

Parameter	Symbol		Specifications		Unit	Conditions
Falameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Supply voltage	V _{CC}	1.60	-	3.63	V	-
Supply voltage	GND	0	-	0	V	-
Operating temperature range	T_use	-40	-	+85	°C	-
CMOS load condition	L_CMOS	-	-	15	pF	-

[3] Frequency Characteristics

(Unless stated otherwise [3] Operating Range)

Parameter	Symbol		Specifications			Conditions
Falanletei	Symbol	Min. Typ. Ma		Max.	Unit	Conditions
Output frequency	fo	-	16.000000	-	MHz	-
Frequency tolerance *1	f_tol	-50	-	+50	×10 ⁻⁶	T_use
Frequency aging	f_age	-3	-	+3	×10 ⁻⁶	+25 °C, First year

*1 Frequency tolerance includes initial frequency tolerance, temperature variation, supply voltage change and load drift.

[4] Electrical Characteristics

(Unless stated otherwise [3] Operating Range)

Parameter	Symbol	Specifications			Unit	Conditions
Parameter	Symbol	Min. Typ.		Max.	Unit	Conditions
Start-up time	t_str	-	-	3.0	ms	t = 0 at 90 % Vcc
Current consumption	I _{CC}	-	-	1.8	mA	No load condition, Vcc = 3.3 V
Stand-by current	I_std	-	-	2.7	μA	<u>ST</u> = GND, Vcc = 3.3 V
	V _{OH}	90 % Vcc	-	-	V	Іон = -4 mA @Vcc = 3.3 V
Output voltage	V _{OL}	-	-	10 % Vcc	V	IoL = 4 mA @Vcc = 3.3 V
Rise time	tr	-	-	3.5	ns	20 % Vcc to 80 % Vcc Level, L_CMOS = 15 pF, Vcc = 1.8 V ± 10 %
Fall time	tf	-	-	3.5	ns	80 % Vcc to 20 % Vcc Level, L_CMOS = 15 pF, Vcc = 1.8 V ± 10 %
Symmetry	SYM	45	-	55	%	50 % Vcc Level, L_CMOS ≤ 15 pF
In put valtage	V _{IH}	80 % Vcc	-	-	V	ST terminal
Input voltage	put voltage V _{IL} -		-	20 % Vcc	V	ST terminal
Output disable time (ST)	tstp_st	-	-	100	ns	\overline{ST} terminal HIGH \rightarrow LOW
Output enable time (ST)	tsta_st	-	-	3	ms	\overline{ST} terminal LOW \rightarrow HIGH

[For other general specifications, please refer to the attached Full Data Sheet below]

Crystal oscillator: SG2016/3225/5032/7050CAN & SG-210STF

Features

- Crystal oscillator (SPXO)
- Frequency:
- 20 standard frequencies (4 MHz to 72 MHz)

CMOS

1.6 V to 3.63 V

-20 °C to +70 °C

-40 °C to +105 °C

Output:

- Supply voltage:
- Operating temperature:

Applications

- IoT, Wearable device
- Data center, Storage
- Medical, Industrial automation

Description

 Pbpppe
 RoHS

 Compliant
 Compliant

 Compliant
 Compliant

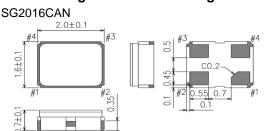
 SG201ECAN
 SG201ECAN
 SG202SCAN
 SG5032CAN
 SG7050CAN

 SG201ECAN
 SG201ECAN
 SG202SCAN
 SG5032CAN
 SG7050CAN
 SG7050CAN

Epson's SGxxxxCAN & SG-210STF are Simple Packaged Crystal Oscillator (SPXO) series with CMOS output. These SPXO's are ideal for variety of applications from IoT, wearables, medical, industrial automation, etc. These SPXO have low current consumption, wide operating voltage from 1.6 V to 3.63 V and wide operating temperature range from -40 °C to 85 °C, in addition operation up to 105 °C is available.

These SPXO's are available in five different package size from 2.0×1.6 mm to 7.0×5.0 mm and available in standard pin out's.

Outline Drawing and Terminal Assignment

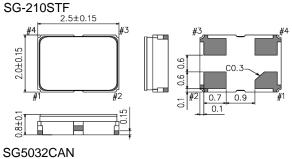


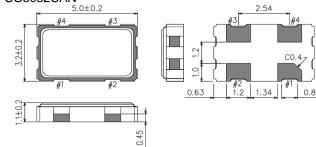
0.45

0.9

0.1

#2 <u>0.85</u> 0.1





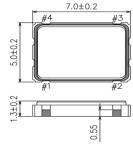
SG7050CAN

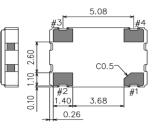
SG3225CAN

2.5±0.2

05±0.1

3.2±0.2





CO 35

Connection	Function			
ST	ST terminal			
	ST function	Osc. Circuit	Output	
	"H" or OPEN	Oscillation	Specified frequency: Enable	
	"L"	Oscillation stop	High impedance: Disable	
GND	GND terminal			
Ουτ	Output terminal			
V _{cc}	V _{cc} terminal			
	ST GND OUT	ST terminal ST function "H" or OPEN "L" GND GND terminal OUT Output terminal	ST terminal ST function Osc. Circuit "If or OPEN Oscillation "L" Oscillation stop GND GND terminal OUT Output terminal	

tor (SPXO) series with CMOS output. nedical, industrial automation, etc. 1.6 V to 3.63 V and wide operating C is available. mm to 7.0 × 5.0 mm and available in

[1] Product Name / Product Number

(1-1) SG2016CAN

(1) Product Name (Standard Form)

<u>SG2016 C AN</u> <u>25.000000MHz</u> <u>T J H A</u> (1) (2) (3) (4) (5) (7)

①Model ②Output (C:CMOS) ③Frequency ④Supply voltage

⑤Frequency tolerance ⑥Operating temperature ⑦Internal identification code ("A" is default)

(4)Supply voltage Refer to Figure 1	⁽⁵⁾ Frequency tolerance / ⁽⁶⁾ Operating temperature
T 1.8 V to 3.3 V Typ.	DB ±25 × 10 ⁻⁶ / -20 °C to +70 °C
K 2.5 V to 3.3 V Typ.	JG ±50 × 10 ⁻⁶ / -40 °C to +85 °C
*Figure 1 is on the next page	JH ±50 × 10 ⁻⁶ / -40 °C to +105 °C

	Frequency	tolerance / Operating te	emperature
Frequency [MHz]	DB	JG	JH
	±25 × 10 ⁻⁶	±50 × 10 ⁻⁶	$\pm 50 \times 10^{-6}$
	-20 °C to +70 °C	-40 °C to +85 °C	-40 °C to +105 °C
4	-	X1G004801003000	X1G004801004900
8	-	X1G004801004500	X1G004801004600
10	-	X1G004801002900	X1G004801002700
12	X1G004801005000	X1G004801000700	X1G004801005100
12.288	X1G004801005200	X1G004801004400	X1G004801005300
14.7456	-	X1G004801005400	X1G004801005500
16	-	X1G004801001400	X1G004801005600
20	X1G004801005700	X1G004801005800	X1G004801001800
24	X1G004801005900	X1G004801000200	X1G004801004000
24.576	-	X1G004801006000	X1G004801003100
25	X1G004801002400	X1G004801001200	X1G004801003500
26	-	X1G004801000300	X1G004801003900
27	-	X1G004801006100	X1G004801002100
32	-	X1G004801006200	X1G004801006300
33.33	-	X1G004801006400	X1G004801006500
33.3333	-	X1G004801002600	X1G004801006600
40	-	X1G004801006700	X1G004801003600
48	X1G004801006800	X1G004801002000	X1G004801006900
50	X1G004801007000	X1G004801001300	X1G004801002800
72	X1G004801007100	X1G004801007200	X1G004801007300

(1-2) SG-210STF

(1) Product Name (Standard Form)

<u>SG-210 STF</u> <u>25.000000MHz</u> Y ① ②③ ④ ⑤

(1)Model (2)Function (S:Standby) (3)Supply voltage

(4) Frequency (5) Frequency tolerance / Operating temperature

(3)S	upply voltage Refer to Figure 1	
Т	1.8 V to 3.3 V Typ.	

*Figure 1 is on th	e next page

⁽⁵⁾ Frequency tolerance / Operating temperature				
S	±25 × 10 ⁻⁶ / -20 °C to +70 °C			
	±50 × 10 ⁻⁶ / -40 °C to +85 °C			
Y	±50 × 10 ⁻⁶ / -40 °C to +105 °C			

	Frequency	emperature	
Frequency [MHz]	S	L	Y
	±25 × 10 ⁻⁶	±50 × 10 ⁻⁶	$\pm 50 \times 10^{-6}$
	-20 °C to +70 °C	-40 °C to +85 °C	-40 °C to +105 °C
4	-	X1G004171000900	X1G004171029900
8	-	X1G004171001500	X1G004171006900
10	-	X1G004171001600	X1G004171036500
12	X1G004171016300	X1G004171001800	X1G004171028000
12.288	X1G004171006100	X1G004171001900	X1G004171036600
14.7456	-	X1G004171002500	X1G004171036700
16	-	X1G004171002700	X1G004171015400
20	X1G004171021800	X1G004171002900	X1G004171023800
24	X1G004171015600	X1G004171003100	X1G004171019700
24.576	-	X1G004171003200	X1G004171036800
25	X1G004171007700	X1G004171003300	X1G004171005900
26	-	X1G004171003400	X1G004171024400
27	-	X1G004171003500	X1G004171025000
32	-	X1G004171004000	X1G004171012700
33.33	-	X1G004171011900	X1G004171030000
33.3333	-	X1G004171012000	X1G004171007500
40	-	X1G004171004500	X1G004171020600
48	X1G004171007800	X1G004171004600	X1G004171036900
50	X1G004171007900	X1G004171004700	X1G004171012600
72	X1G004171037000	X1G004171012400	X1G004171037100

(1-3) SG3225CAN

(1) Product Name (Standard Form)

<u>SG3225 C AN</u> <u>25.000000MHz</u> <u>T J H A</u> (1) (2) (3) (4) (6) (7)

①Model ②Output (C:CMOS) ③Frequency ④Supply voltage

⑤Frequency tolerance ⑥Operating temperature ⑦Internal identification code ("A" is default)

4 Supply voltage Refer to Figure 1		⁽⁵⁾ Frequency tolerance / ⁽⁶⁾ Operating temperature			
T 1.8 V to 3.3 V Typ.		±25 × 10 ⁻⁶ / -20 °C to +70 °C			
K 2.5 V to 3.3 V Typ.	JG	±50 × 10 ⁻⁶ / -40 °C to +85 °C			
*Figure 1 is on the next page	JH	±50 × 10 ⁻⁶ / -40 °C to +105 °C			

	Frequency	tolerance / Operating temperature		
Fraguanay [MHz]	DB	JG	JH	
Frequency [MHz]	±25 × 10 ⁻⁶	±50 × 10 ⁻⁶	±50 × 10 ⁻⁶	
	-20 °C to +70 °C	-40 °C to +85 °C	-40 °C to +105 °C	
4	-	X1G005961001115	X1G005961001215	
8	-	X1G005961000415	X1G005961001315	
10	-	X1G005961000515	X1G005961001415	
12	X1G005961001515	X1G005961000615	X1G005961001615	
12.288	X1G005961001715	X1G005961001815	X1G005961001915	
14.7456	-	X1G005961002015	X1G005961002115	
16	-	X1G005961002215	X1G005961002315	
20	X1G005961002415	X1G005961000715	X1G005961002515	
24	X1G005961002615	X1G005961000115	X1G005961002715	
24.576	-	- X1G005961000815		
25	X1G005961002915	X1G005961000215	X1G005961003015	
26			X1G005961003215	
27			X1G005961003415	
32	-	X1G005961003515	X1G005961003615	
33.33	-	X1G005961003715	X1G005961003815	
33.3333	-	X1G005961003915	X1G005961004015	
40	-	X1G005961000915	X1G005961004115	
48	X1G005961004215	X1G005961000315	X1G005961004315	
50	X1G005961004415	X1G005961001015	X1G005961004515	
72	X1G005961004615	X1G005961004715	X1G005961004815	

(1-4) SG5032CAN

(1) Product Name (Standard Form)

<u>SG5032 C AN</u> <u>25.000000MHz</u> <u>T J H A</u> ① ② ③ ④ ⑤⑦

①Model ②Output (C:CMOS) ③Frequency ④Supply voltage

⑤Frequency tolerance ⑥Operating temperature ⑦Internal identification code ("A" is default)

⁽⁴⁾ Supply voltage Refer to Figure 1	(5)F	requency tolerance / ⁶ Operating temperature
T 1.8 V to 3.3 V Typ.		±25 × 10 ⁻⁶ / -20 °C to +70 °C
K 2.5 V to 3.3 V Typ.	JG	±50 × 10 ⁻⁶ / -40 °C to +85 °C
*Figure 1 is on the next page	JH	±50 × 10 ⁻⁶ / -40 °C to +105 °C

	Frequency	tolerance / Operating te	emperature	
	DB	JG	JH	
Frequency [MHz]	±25 × 10 ⁻⁶	$\pm 50 \times 10^{-6}$	±50 × 10 ⁻⁶	
	-20 °C to +70 °C	-40 °C to +85 °C	-40 °C to +105 °C	
4	-	X1G004451003400	X1G004451019600	
8	-	X1G004451002100	X1G004451019700	
10	-	X1G004451001300	X1G004451017800	
12	X1G004451019800	X1G004451002800	X1G004451019900	
12.288	X1G004451020000	X1G004451000100	X1G004451020100	
14.7456	-	X1G004451001900	X1G004451020200	
16	-	X1G004451000200	X1G004451020300	
20	X1G004451020400	X1G004451001100	X1G004451020500	
24	X1G004451017200	X1G004451000300	X1G004451020600	
24.576	-	- X1G004451002900		
25	X1G004451009700	X1G004451000400	X1G004451020800	
26	-	X1G004451008200	X1G004451020900	
27	7 - X1G004451000500		X1G004451021000	
32	-	X1G004451001400	X1G004451021100	
33.33	-	X1G004451021200	X1G004451021300	
33.3333	-	X1G004451016700	X1G004451021400	
40	-	X1G004451001200	X1G004451021500	
48	X1G004451014900	X1G004451000700	X1G004451011200	
50	X1G004451011500	X1G004451000800	X1G004451003600	
72	X1G004451021600	X1G004451021700	X1G004451021800	

(1-5) SG7050CAN

(1) Product Name (Standard Form)

<u>SG7050 CAN</u> <u>25.000000MHz</u> <u>T J H A</u> (1) 2 3 4567

①Model ②Output (C:CMOS) ③Frequency ④Supply voltage

⑤Frequency tolerance ⑥Operating temperature ⑦Internal identification code ("A" is default)

4 Supply voltage Refer to Figure 1	⁽⁵⁾ Frequency tolerance / ⁽⁶⁾ Operating temperature
T 1.8 V to 3.3 V Typ.	DB ±25 × 10 ⁻⁶ / -20 °C to +70 °C
K 2.5 V to 3.3 V Typ.	JG ±50 × 10 ⁻⁶ / -40 °C to +85 °C
*Figure 1 is on the next page	JH ±50 × 10 ⁻⁶ / -40 °C to +105 °C

	Frequency	tolerance / Operating te	emperature	
	DB	JG	JH	
Frequency [MHz]	±25 × 10 ⁻⁶	±50 × 10 ⁻⁶	$\pm 50 \times 10^{-6}$	
	-20 °C to +70 °C	-40 °C to +85 °C	-40 °C to +105 °C	
4	-	X1G004481005100	X1G004481025200	
8	-	X1G004481001400	X1G004481025300	
10	-	X1G004481000500	X1G004481025400	
12	X1G004481025500	X1G004481000600	X1G004481025600	
12.288	X1G004481025700	X1G004481000100	X1G004481025800	
14.7456	-	X1G004481002500	X1G004481025900	
16	-	X1G004481000700	X1G004481026000	
20	X1G004481012800	X1G004481000800	X1G004481026100	
24	X1G004481002200	X1G004481000200	X1G004481026200	
24.576	-	X1G004481001600	X1G004481026300	
25	6 - X1G004481003500		X1G004481026400	
26			X1G004481026500	
27			X1G004481026600	
32	-	X1G004481000900	X1G004481026700	
33.33	-	X1G004481017900	X1G004481026800	
33.3333	-	X1G004481003300	X1G004481026900	
40	-	X1G004481001500	X1G004481027000	
48	X1G004481022600	X1G004481001100	X1G004481027100	
50	X1G004481011200	X1G004481001200	X1G004481016000	
72	X1G004481027200	X1G004481018300	X1G004481027300	

[2] Absolute Maximum Ratings

Parameter	Symbol		Specification		Unit	Conditions
Falameter	Symbol	Min.	Тур.	Max.	Offic	Conditions
Maximum supply voltage	V _{CC}	-0.3	-	4	V	
Input voltage	Vin	-0.3	-	V _{CC} + 0.3	V	ST terminal
Storago tomporaturo rango		-55	-	+125	°C	SG2016CAN, SG3225CAN
Storage temperature range	T_stg	-40	-	+125	°C	All other

[3] Operating Range

Parameter	Symbol		Specification		Unit	Conditions
Falametei	Symbol	Min.	Тур.	Max.	Unit	Conditions
		1.6	-	3.63	V	fo ≤ 50 MHz, T_use = +105 °C Max.
Supply voltage	V _{cc}	1.71	-	3.63	V	fo = 72 MHz, T_use = +85 °C Max.
		2.25	-	3.63	V	fo = 72 MHz, T_use = +105 °C Max.
Supply voltage	GND	0.0	0.0	0.0	V	
		-20	+25	+70	°C	
Operating temperature range (Refer to Figure 1)	T_use	-40	+25	+85	°C	
		-40	+25	+105	°C	
CMOS load condition	L_CMOS	-	-	15	pF	

* Power supply startup time (0 %V_{CC} \rightarrow 90 %V_{CC}) should be more than 150 µs * A 0.01 µF to a 0.1 µF bypass capacitor should be connected between V_{CC} and GND pins located close to the device



Please note that Supply voltage range (V $_{\rm CC})$ depends on Output frequency(fo) and upper limit of Operating temperature(T_use Max.).

Figure 1: The upper limit of Operating temperature and the related conditions

[4] Frequency Characteristics

(Unless stated otherwise [3] Operating Range)

Parameter	Symbol		Specification		Unit	Conditions	
Farameter	Symbol	Min.	Тур.	Max.	Offic	Conditions	
Output frequency	fo	24.576, 25, 2	12.288, 14.745 26, 27, 32, 33.3 40, 48, 50, 72	33, 33.3333,	MHz		
		-50	-	+50	×10 ⁻⁶	T_use = -20 °C to +70 °C	
Frequency tolerance *1	olerance *1 f_tol			+100	×10 ⁻⁶	T_use = -40 °C to +105 °C T_use = -40 °C to +85 °C *2	
Frequency aging	f_age	-3		+3	×10 ⁻⁶	T_use = +25 °C, First year	

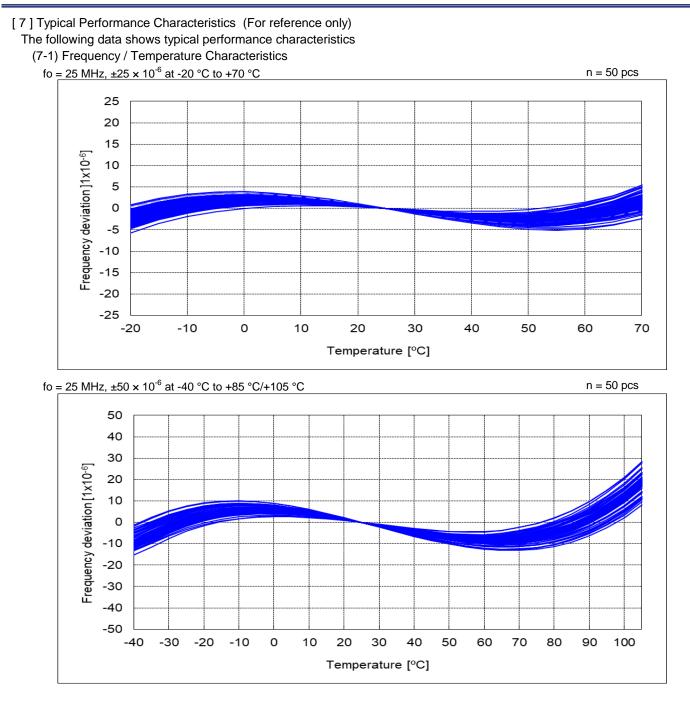
*1 Frequency tolerance includes initial frequency tolerance, frequency / temperature characteristics, frequency / voltage coefficient, and frequency / load coefficient

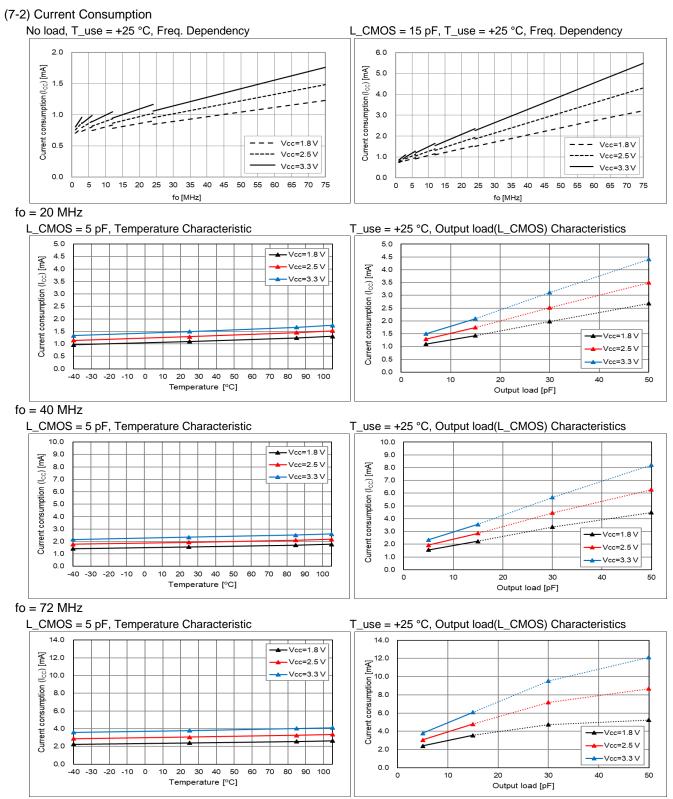
*2 This temperature range is only for fo = 72 MHz

Parameter	Symbol		Specification	n T	Unit	Conditions
Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Start-up time	t_str	-	-	3	ms	t = 0 at 90 %V _{CC}
Current concurrentian (No. lood)		-	-	1.5	mA	4 MHz ≤ fo ≤ 20 MHz
Current consumption (No load) V _{CC} = 1.8 V ± 10 %		-	-	1.8	mA	20 MHz < fo ≤ 40 MHz
Vec = 1.6 V ± 10 /6		-	-	2.1	mA	40 MHz < fo ≤ 50 MHz
$V_{CC} = 1.8 \text{ V} \pm 5 \%$		-	-	2.4	mA	fo = 72 MHz
		-	-	1.6	mA	4 MHz ≤ fo ≤ 20 MHz
Current consumption (No load)		-	-	2.0	mA	20 MHz < fo ≤ 40 MHz
$V_{CC} = 2.5 \text{ V} \pm 10 \%$	I _{cc}	-	-	2.4	mA	40 MHz < fo ≤ 50 MHz
		-	-	2.8	mA	fo = 72 MHz
	_	-	-	1.8	mA	4 MHz ≤ fo ≤ 20 MHz
Current consumption (No load)		-	-	2.2	mA	20 MHz < fo ≤ 40 MHz
$V_{CC} = 3.3 \text{ V} \pm 10 \%$		-	-	2.6	mA	40 MHz < fo ≤ 50 MHz
		-	-	3.0	mA	fo = 72 MHz
	I_std	-	-	2.1	μA	$V_{CC} = 1.8 V \pm 10 \% \text{ or } \pm 5 \%,$ $\overline{ST} = GND$
Stand-by current		-	-	2.5	μA	$V_{CC} = 2.5 \text{ V} \pm 10 \text{ \%}, \overline{ST} = \text{GND}$
		-	-	2.7	μA	$V_{CC} = 3.3 \text{ V} \pm 10 \%, \overline{ST} = \text{GND}$
	V _{OH}	90 % V _{CC}	-	-	V	Load current condition
	V _{OL}	-	-	10 % V _{cc}	V	_{OH} -1.5 mA -3 mA -4 mA _{OL} 1.5 mA 3 mA 4 mA
Dutput voltage	V _{OH}	V _{CC} - 0.4	-	-	V	Load current condition
	V _{OL}	-	-	0.4	V	I _{OH} -3 mA -4 mA -6 mA I _{OL} 3 mA 4 mA 6 mA
Symmetry	SYM	45	50	55	%	50 % V _{CC} level, L_CMOS ≤ 15 pF
Diag time/Eall time	tr / tf	-	-	3	ns	$V_{CC} = 2.5 V \text{ or } 3.3 V \pm 10 \%$, 20 % V_{CC} to 80 % V_{CC} Level, L_CMOS = 15 pF
Rise time/Fall time	tr / tf	-	-	3.5	ns	$V_{CC} = 1.8 V \pm 10 \% \text{ or } \pm 5 \%$, 20 % V_{CC} to 80 % V_{CC} Level, L_CMOS = 15 pF
	V _{IH}	80 % Vcc	-	-	V	
nput voltage	VIL	-	-	20 % Vcc	V	ST terminal
Dutput disable time (ST)	tstp_st	-	-	100	ns	\overline{ST} terminal HIGH \rightarrow LOW
Dutput enable time (ST)	tsta_st	-	-	3	ms	\overline{ST} terminal LOW \rightarrow HIGH

[6] Thermal resistance (For reference only)

Parameter	Symbol		Specification		Linit	Conditions
Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Junction temperature	Tj	-	-	+125	°C	
		-	9.8	-	°C/W	SG2016CAN
		-	15.2	-	°C/W	SG-210STF
Junction to case	Өјс	-	23.1	-	°C/W	SG3225CAN
		-	16.1	-	°C/W	SG5032CAN
		-	28.0	-	°C/W	SG7050CAN
		-	99.6	-	°C/W	SG2016CAN
		-	91.9	-	°C/W	SG-210STF
Junction to ambient	θја	-	103.8	-	°C/W	SG3225CAN
		-	82.5	-	°C/W	SG5032CAN
		-	78.8	-	°C/W	SG7050CAN





* Output load condition under L_CMOS > 15 pF (dotted line area) is not guaranteed, and the data is for reference. The actual current consumption is the total of the current under the condition of no load and the current to drive the output load (fo x L_CMOS x V_{CC}). To reduce the current consumption, it is effective to use lower frequency, lower supply voltage and lower output load.

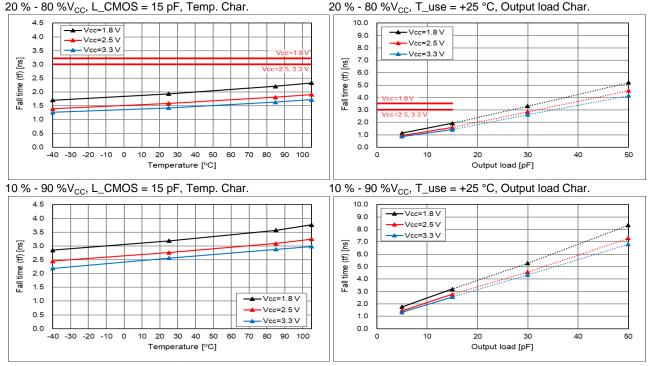
(7-3) Rise Time / Fall Time

fo = 20 MHz, Rise Time



* Output load condition under L_CMOS > 15 pF (dotted line area) is not guaranteed, and the data is for reference.

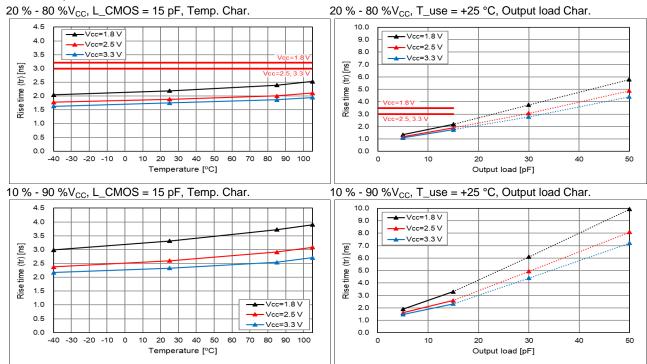
fo = 20 MHz, Fall Time



* Output load condition under L_CMOS > 15 pF (dotted line area) is not guaranteed, and the data is for reference.

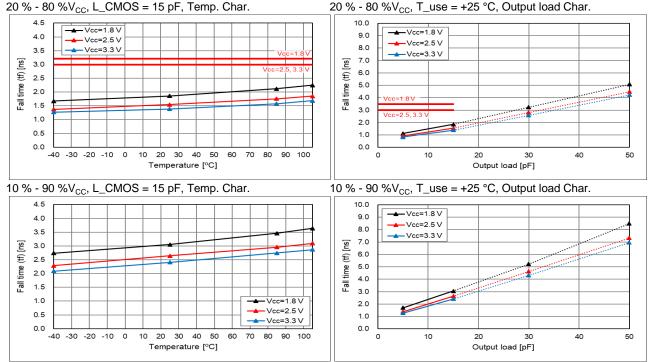
(7-3) Rise Time / Fall Time [cont'd]

fo = 40 MHz, Rise Time



* Output load condition under L_CMOS > 15 pF (dotted line area) is not guaranteed, and the data is for reference.

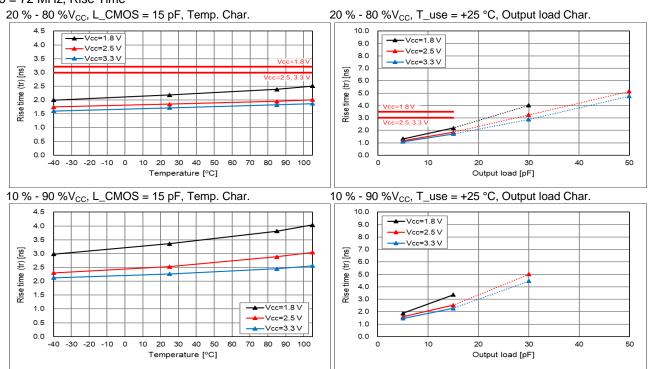
fo = 40 MHz, Fall Time



* Output load condition under L_CMOS > 15 pF (dotted line area) is not guaranteed, and the data is for reference.

(7-3) Rise Time / Fall Time [cont'd]

fo = 72 MHz, Rise Time



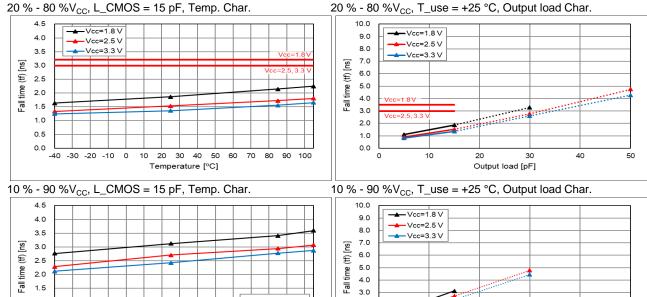
* Output load condition under L_CMOS > 15 pF (dotted line area) is not guaranteed, and the data is for reference. There are some missing data in the graph. It is unmeasurable because of low amplitude under the condition of L_CMOS > 15 pF.

fo = 72 MHz, Fall Time

1.0

0.5

-40 -30 -20 -10 0



2.0

1.0

0.0

0

10

20

Output load [pF]

30

40

50

* Output load condition under L_CMOS > 15 pF (dotted line area) is not guaranteed, and the data is for reference. There are some missing data in the graph. It is unmeasurable because of low amplitude under the condition of L_CMOS > 15 pF.

80

20 30

40 50 60 70

Temperature [°C]

10

. Vcc=1.8 ∖

Vcc=2.5 V

-Vcc=3.3 V

90 100

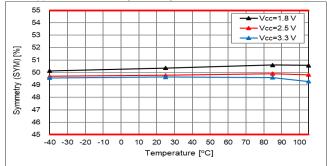
(7-4) Symmetry

fo = 20 MHz

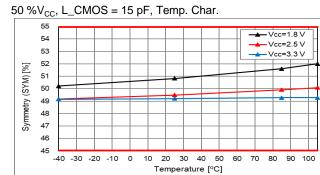


fo = 40 MHz

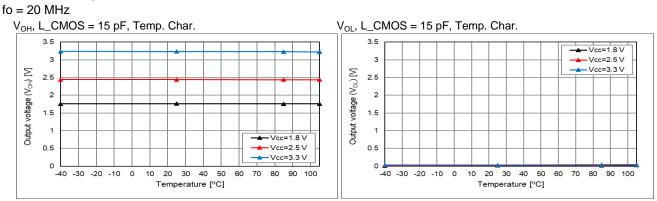
50 %V_{CC}, L_CMOS = 15 pF, Temp. Char.



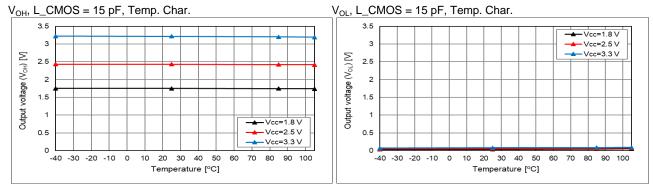
fo = 72 MHz



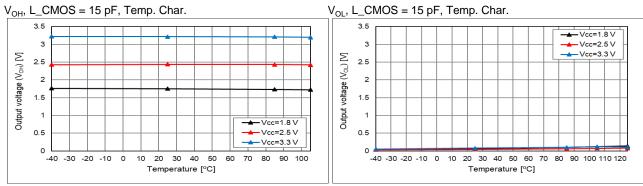
(7-5) Output Voltage

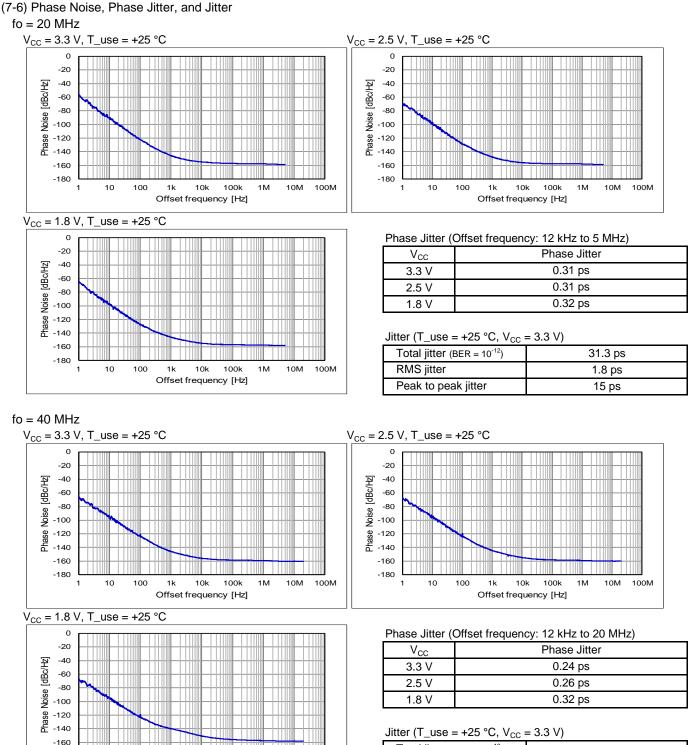


fo = 40 MHz



fo = 72 MHz





			,
		Total jitter (BER = 10 ⁻¹²)	22.3 ps
м	RMS jitter	1.8 ps	
		Peak to peak jitter	16 ps

-180

1

10

100

1k

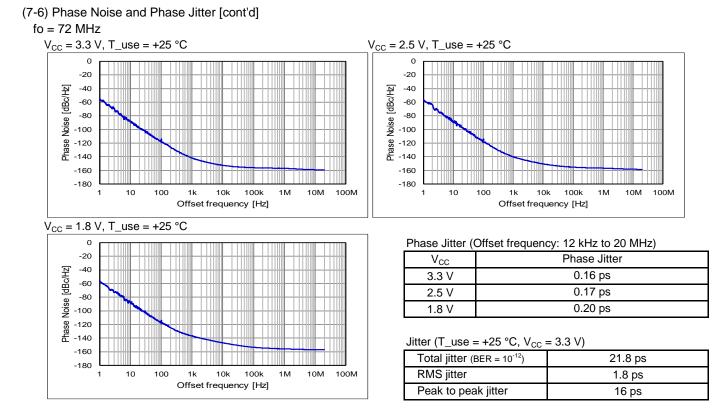
10k

Offset frequency [Hz]

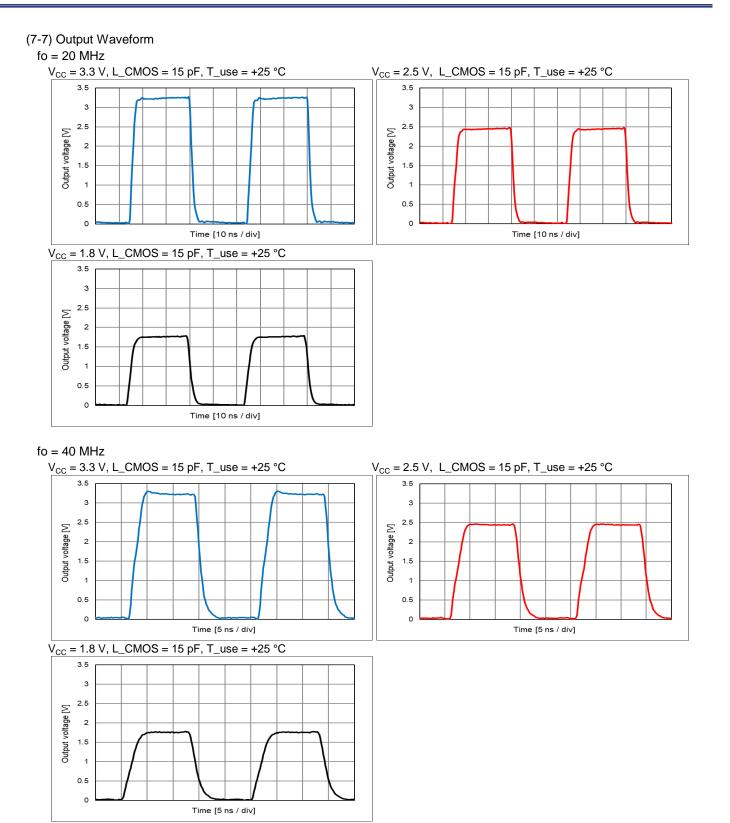
100k

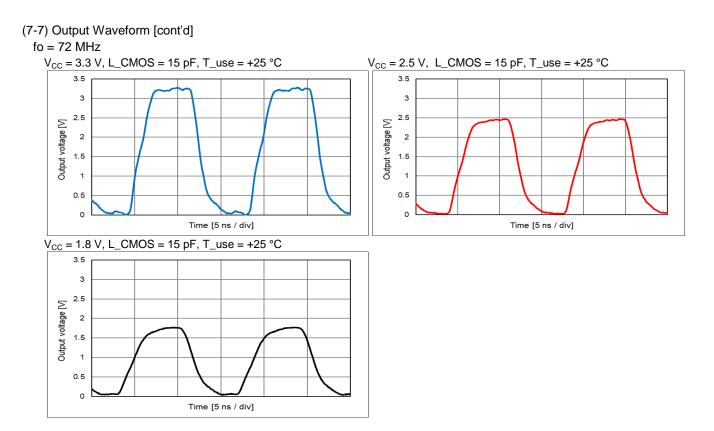
1M

10M 100



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[8] Test Circuit

(8-1) Waveform Observation



(8-2) Current Consumption Test



*Standby current test should be $\overline{ST} = GND$.

- (8-3) Condition
- (1) Oscilloscope

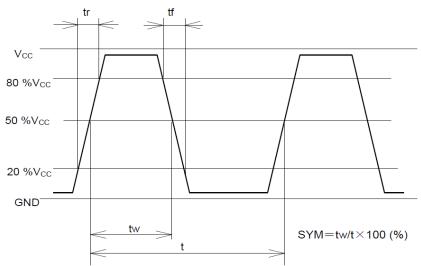
The bandwidth should be minimum 5 times wider than measurement frequency

- The probe ground should be placed closely to the test point and the lead length should be as short as possible
 - * It is recommended to use miniature socket. (Don't use earth lead.)
- (2) L_CMOS includes probe capacitance.
- (3) A 0.01 μF to a 0.1 μF bypass capacitor should be connected between V $_{CC}$ and GND pins located close to the device
- (4) Use a current meter with a low internal impedance
- (5) Power Supply

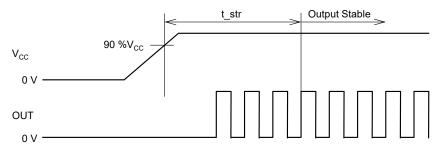
Power supply startup time (0 $\%V_{CC} \rightarrow 90 \%V_{CC}$) should be more than 150 µs Power supply impedance should be as low as possible

(8-4) Timing Chart

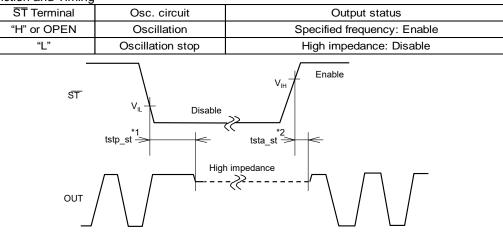
(1) Output Waveform and Level



(2) Output Frequency Timing



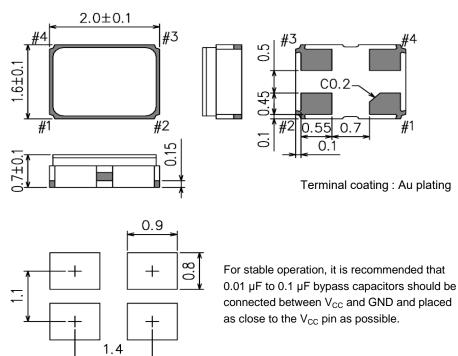
(3) ST Function and Timing



- *1 The period from $\overline{ST} = V_{IL}$ to OUT = High impedance (Disable)
- *2 The period from \overline{ST} = $V_{I\!H}$ to OUT = Enable
- * Judge of starting output: $V_{0H} \ge 80 \ \text{W}_{CC}$, $V_{0L} \le 20 \ \text{W}_{VCC}$, fout is within fo $\pm 1 \ 000 \ \times \ 10^{-6}$ * \overline{ST} terminal voltage level should not exceed supply voltage when using \overline{ST} function.

Please note that ST rise time should not exceed supply voltage rise time at the start-up.

[9] Outline Drawing and Recommended Footprint (9-1) SG2016CAN



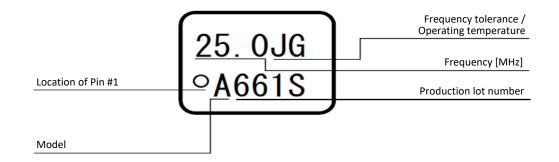
<u><</u>___>

Reference Weight Typ.: 9.9 mg

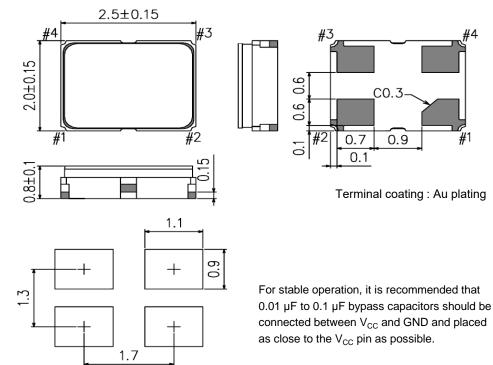
Terminal Assignment

	Pin #	Connection	Function						
			ST terminal						
	#1	ST	\overline{ST} function	Osc. Circuit	Output				
	#1	51	"H" or OPEN	Oscillation	Specified frequency: Enable				
			"L"	Oscillation stop	High impedance: Disable				
	#2	GND	GND terminal						
	#3	OUT	Output terminal						
	#4	V _{cc}	V _{cc} terminal						

Marking



(9-2) SG-210STF



Units: mm

Reference Weight Typ.: 14 mg

Terminal Assignment

Pin #	Connection	Function		
#1	ST	ST terminal		
		\overline{ST} function	Osc. Circuit	Output
		"H" or OPEN	Oscillation	Specified frequency: Enable
		"L"	Oscillation stop	High impedance: Disable
#2	GND	GND terminal		
#3	OUT	Output terminal		
#4	V _{cc}	V _{cc} terminal		

Marking



(9-3) SG3225CAN

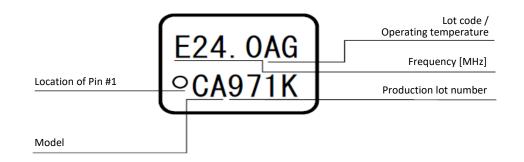


Reference Weight Typ.: 25 mg

Terminal Assignment

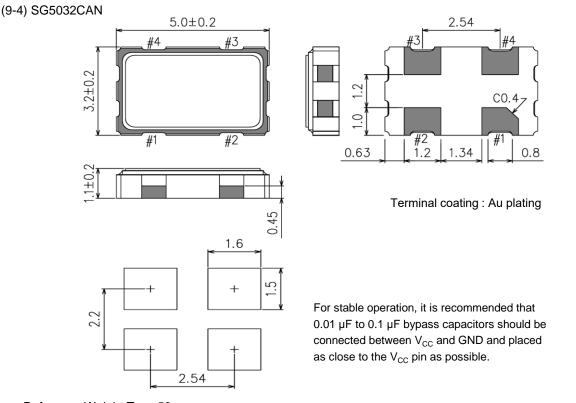
<u> </u>					
	Pin #	Connection	Function		
	5	ST terminal	ST terminal		
	#1	ST	\overline{ST} function	Osc. Circuit	Output
	#1 51	51	"H" or OPEN	Oscillation	Specified frequency: Enable
		"L"	Oscillation stop	High impedance: Disable	
	#2	GND	GND terminal		
	#3	OUT	Output termina	1	
	#4	V _{cc}	V _{cc} terminal		

Marking



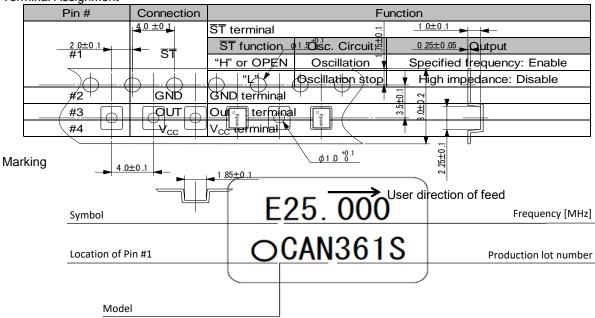
Units: mm

Units: mm

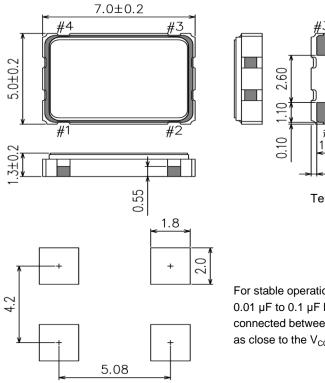


Reference Weight Typ.: 52 mg

Terminal Assignment



(9-5) SG7050CAN



For stable operation, it is recommended that 0.01 μF to 0.1 μF bypass capacitors should be connected between V_{CC} and GND and placed as close to the V_{CC} pin as possible.

Reference Weight Typ.: 147 mg

Terminal Assignment

···-						
	Pin #	Connection	Function			
Ī	S	ST terminal	T terminal			
	#1	ST	\overline{ST} function	Osc. Circuit	Output	
	#1		"H" or OPEN	Oscillation	Specified frequency: Enable	
			"L"	Oscillation stop	High impedance: Disable	
	#2	GND	GND terminal			
	#3	OUT	Output termina	l		
ſ	#4	V _{cc}	V _{cc} terminal			

Marking

Symbol	E25.000	Frequency [MHz]
Location of Pin #1	OCAN361S	Production lot number
Model		

[10] Moisture Sensitivity Level and Electro-Static Discharge Ratings

(10-1) Moisture Sensitivity Level (MSL)

Parameter	Specification	Conditions
MSL	LEVEL 1	IPC/JEDEC J-STD-020D.1

(10-2) Electro-Static Discharge (ESD)

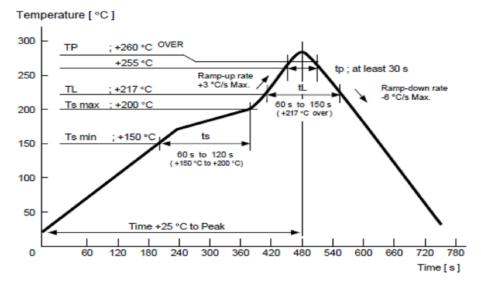
Parameter	Specification	Conditions
HBM	2 000 V Min.	EIAJ ED-4701-1 C111A, 100 pF, 1.5 kΩ, 3 times
MM	200 V Min.	EIAJ ED-4701-1 C111, 200 pF, 0 Ω, 1 time
CDM	750 V Min	AEC-Q100-011 (DCDM) * only for SG2016CAN

(10-3) Latch-Up

Parameter	Specification	Conditions
Latch-up	100 mA Min.	EIAJ ED-4701-1 C113

[11] Reflow Profiles

IPC/JEDEC J-STD-020D.1



[12] Packing Information

(12-1) SG2016CAN

(1) Packing Quantity

The last two digits of the Product Number (X1G004801xxxx \underline{xx}) are a code that defines the packing quantity. The standard is "00" for a 3 000 pcs/Reel.

(2) Taping Specification

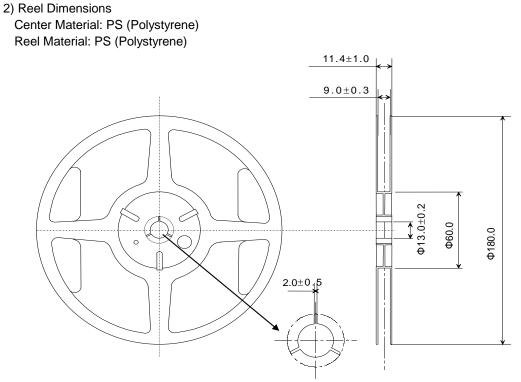
Subject to EIA-481, IEC-60286 and JIS C0806

1) Tape Dimensions

Carrier Tape Material: PS (Polystyrene)

Top Tape Material: PET (Polyethylene Terephthalate) +PE (Polyethylene)

Units: mm



Units: mm

3) Storage Environment

We recommend to keep less than +30 °C and 85 %RH of humidity in a packed condition, and to use it less than 6 months after delivery.

(12-2) SG-210STF

(1) Packing Quantity

The last two digits of the Product Number (X1G004171xxxx<u>xx</u>) are a code that defines the packing quantity. The standard is "00" for a 3 000 pcs/Reel.

(2) Taping Specification

Subject to EIA-481, IEC-60286 and JIS C0806

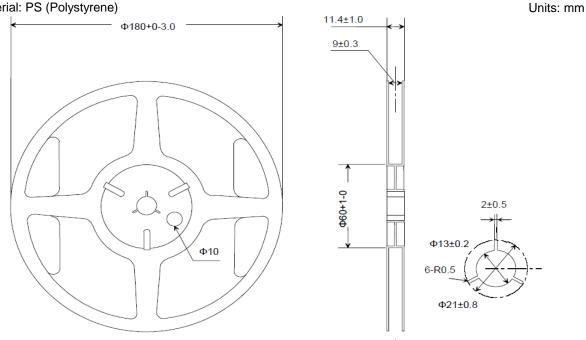
- 1) Tape Dimensions
 - Carrier Tape Material: PS (Polystyrene)

Top Tape Material: PET (Polyethylene Terephthalate) +PE (Polyethylene)

10P: 40.0±0.1 1.15±0.1 .75±0.1 2.0±0.1 +0.1 0.25 ± 0.05 Φ1.5 -0 4.0±0.1 .5±0.1 8.0±0.2 Epsor Epson 840 +0.1 4.0±0.1 Top tap <u>Φ1</u>.0-0 User direction of feed

2) Reel Dimensions

Center Material: PS (Polystyrene) Reel Material: PS (Polystyrene)



3) Storage Environment

We recommend to keep less than +30 °C and 85 %RH of humidity in a packed condition, and to use it less than 6 months after delivery.

Units: mm

Units: mm

(12-3) SG3225CAN

(1) Packing Quantity

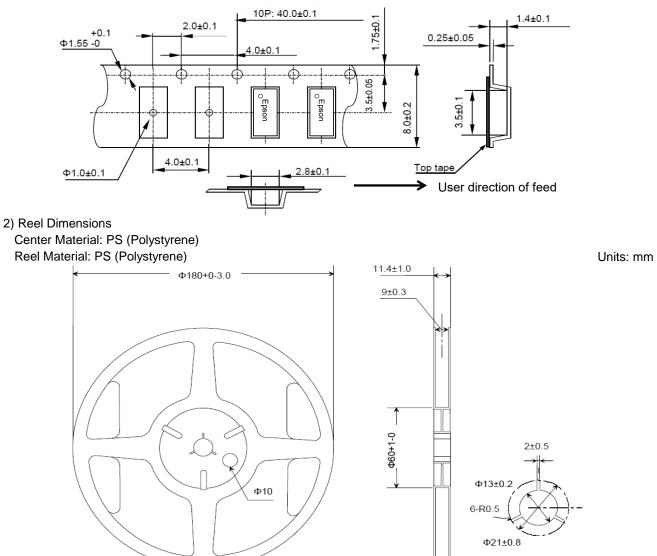
The last two digits of the Product Number (X1G005961xxxx \underline{xx}) are a code that defines the packing quantity. The standard is "15" for a 2 000 pcs/Reel.

(2) Taping Specification

Subject to EIA-481, IEC-60286 and JIS C0806

- 1) Tape Dimensions
 - Carrier Tape Material: PS (Polystyrene)

Top Tape Material: PET (Polyethylene Terephthalate) +PE (Polyethylene)



3) Storage Environment

We recommend to keep less than +30 °C and 85 %RH of humidity in a packed condition, and to use it less than 6 months after delivery.

(12-4) SG5032CAN

(1) Packing Quantity

The last two digits of the Product Number (X1G004451xxxx \underline{xx}) are a code that defines the packing quantity. The standard is "00" for a 1 000 pcs/Reel.

(2) Taping Specification

Subject to EIA-481, IEC-60286 and JIS C0806

- 1) Tape Dimensions
 - Carrier Tape Material: PS (Polystyrene)

Top Tape Material: PET (Polyethylene Terephthalate) +PE (Polyethylene)

1.4±0.1 10P: 40±0.1 1.75±0.1 2.0±0.1 +0.1 Φ1.5 -0.0 0.3±0.05 4.0±0.1 ¢ ¢ ¢ φ φ 5.5±0.1 12.0±0.2 oEpson 0 Epson 5.4±0.³ +0.1 Φ1.5 -0.0 8.0±0.1 Тор Таре 3.5±0.1 User direction of feed

2) Reel Dimensions

Center Material: PS (Polystyrene) Reel Material: PS (Polystyrene)

Units: mm



3) Storage Environment

We recommend to keep less than +30 °C and 85 %RH of humidity in a packed condition, and to use it less than 6 months after delivery.

Units: mm

(12-5) SG7050CAN

(1) Packing Quantity

The last two digits of the Product Number (X1G004481xxxx \underline{xx}) are a code that defines the packing quantity. The standard is "00" for a 1 000 pcs/Reel.

(2) Taping Specification

Subject to EIA-481, IEC-60286 and JIS C0806

- 1) Tape Dimensions
 - Carrier Tape Material: PS (Polystyrene)

Top Tape Material: PET (Polyethylene Terephthalate) +PE (Polyethylene)

1.75±0.1 2.0±0.1 10P: 40.0±0.15 +0.1 Φ1.5 -0 2.0±0.1 0.3±0.05 4.0±0.1 0 7.5±0.1 16.0±0.2 oEpson Epson t 7.4±0. +0.1 8.0±0.1 5.1±0.1 Top tape Φ1.55-0 User direction of feed

2) Reel Dimensions

Center Material: PS (Polystyrene) Reel Material: PS (Polystyrene)

Units: mm

Units: mm



3) Storage Environment

We recommend to keep less than +30 °C and 85 %RH of humidity in a packed condition, and to use it less than 6 months after delivery.

[13] Handling Precautions

Prior to using this product, please carefully read the section entitled "Precautions" on our Web site (https://www5.epsondevice.com/en/information/#precaution) for instructions on how to handle and use the product properly to ensure optimal performance of the product in your equipment. Before using the product under any conditions other than those specified therein,

please consult with us to verify and confirm that the performance of the product will not be negatively affected by use under such conditions.

In addition to the foregoing precautions, in order to avoid the deteriorating performance of the product, we strongly recommend that you DO NOT use the product under ANY of the following conditions:

- (1) Do not expose this product to excessive mechanical shock or vibration.
- (2) This product can be damaged by mechanical shock during the soldering process depending on the equipment used, process conditions, and any impact forces experienced. Always follow appropriate procedures, particularly when changing the assembly process in any way and be sure to follow applicable process qualification standards before starting production.
- (3) These devices are sensitive to ESD, use appropriate precautions during handling, assembly, test, shipment, and installation.
- (4) The use of ultrasonic technology for cleaning, bonding, etc. can damage the Xtal unit inside this product.
- Please carefully check for this consideration before using ultrasonic equipment for volume production with this product. (5) Noise and ripple on the power supply may have undesirable affects on operation and cause degradation of phase noise
- characteristics. Evaluate the operation of this device with appropriate power supplies carefully before use.
 (6) When applying power, ensure that the supply voltage increases monotonically for proper operation.
 On power down, do not reapply power until the supplies, bypass capacitors, and any bulk capacitors are complete
- On power down, do not reapply power until the supplies, bypass capacitors, and any bulk capacitors are completely discharged since that may cause the unit to malfunction.
- (7) Aging specifications are estimated from environmental reliability tests and expected frequency variation over time. They do not provide a guarantee of aging over the product lifecycle.
- (8) The metal cap on top of the device is directly connected to the GND terminal. Take necessary precautions to prevent any conductor not at ground potential from contacting the cap as that could cause a short circuit to GND.
- (9) Do not route any signal lines, supply voltage lines, or GND lines underneath the area where the oscillators are mounted including any internal layers and on the opposite side of the PCB. To avoid any issues due to interference of other signal lines, please take care not to place signal lines near the product as this may have an adverse affect on the performance of the product.
- (10) A bypass capacitor of the recommended value(s) must be connected between the V_{CC} and GND terminals of the product. Whenever possible, mount the capacitor(s) on the same side of the PCB and as close to the product as possible to keep the routing traces short.
- (11) Power supply connections to V_{CC} and GND pins should be routed as thick as possible while keeping the high frequency impedance low in order to get the best performance.
- (12) The use of a filter or similar element in series with the power supply connections to protect from electromagnetic radiation noise may increase the high frequency impedance of the power supply line and may cause the oscillator to not operate properly. Please verify the design to ensure sufficient operational margin prior to use.
- (13) Keep PCB routing from the output terminal(s) to the load as short as possible for best performance.
- (14) The Enable (ST) input terminal is high impedance and so susceptible to noise. Connect it to a low impedance source when used and when not used it is recommended to connect it to Vcc for active high inputs and GND for active low inputs.
- (15) Do not short the output to GND as that will damage the product. Always use with an appropriate load resistor connected.
- (16) This product should be reflowed no more than 3 times.
 If rework is needed after reflow, please correct it with a soldering iron with the tip set for a temperature of +350 °C or less and only contact each terminal once and for no more than 5 seconds.
 If this product is mounted on the bottom of the board during a reflow please check that it soldered down properly afterwards.

[Availability of mounting con	ditions]
Reflow on the board	Avallable
Reflow under the board	The parts may fall. Please judge whether it is possible to implement.
Soldering pot/bath (Dip soldering system, Flow soldering system)	Not Avallable
Soldering iron	Avallable

- (17) Product failures during the warranty period only apply when the product is used according to the recommended operating conditions described in the specifications. Products that have been opened for analysis or damaged will not be covered. It is recommended to store and use in normal temperature and humidity environments described in the specifications to ensure frequency accuracy and prevent moisture condensation. If the product is stored for more than one year, please confirm the pin solderability prior to use.
- (18) If the oscillation circuit is exposed to condensation, the frequency may change or oscillation may stop. Do not use in any conditions where condensation occurs.
- (19) Do not store or use the product in an environment where it can be exposed to chemical substances that are corrosive to metal or plastics such as salt water, organic solvents, chemical gasses, etc. Do not use the product when it is exposed to sunlight, dust, corrosive gasses, or other materials for long periods of time.
- (20) When using water-soluble solder flux make sure to completely remove the flux residue after soldering. Pay particular attention when the residues contain active halogens which will negatively affect the product and its performance.
- (21) Terminals on the side of the product are internally connected to the IC, be careful not to cause short-circuits or reduce the insulation resistance of them in any way.
- (22) Should any customer use the product in any manner contrary to the precautions and/or advice herein, such use shall be done at the customer's own risk.

PROMOTION OF ENVIRONMENTAL MANAGEMENT SYSTEM CONFORMING TO INTERNATIONAL STANDARDS

At Seiko Epson, all environmental initiatives operate under the Plan-Do-Check-Action (PDCA) cycle designed to achieve continuous improvements. The environmental management system (EMS) operates under the ISO 14001 environmental management standard. All of our major manufacturing and non-manufacturing sites, in Japan and overseas, completed the acquisition of ISO 14001 certification.

WORKING FOR HIGH QUALITY In order provide high quality and reliable products and services than meet customer needs, Seiko Epson made early efforts towards obtaining ISO9000 series certification and has acquired ISO9001 for all business establishments in Japan and abroad. We have also acquired IATF 16949 certification that is requested strongly by major manufacturers as standard.

Explanation of marks used in this datasheet

ISO 14000 is an international standard for environmental management that was established by the International Standards Organization in 1996 against the background of growing concern regarding global warming, destruction of the ozone layer, and global deforestation.

IATF 16949 is the international standard that added the sector-specific supplemental requirements for automotive industry based on ISO9001.

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RoHS	 Complies with EU RoHS directive. *About the products without the Pb-free mark. Contains Pb in products exempted by EU RoHS directive (Contains Pb in sealing glass, high melting temperature type solder or other)

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